



Ultra Thin Secondary Electron Emission Sensors for Beam Monitoring

Nicola Minafra (The University of Kansas (US))



Ruggero Caravita^o
Michael Doser*
Blerina Gkotse*
Stefan Haider*
Robert Loos*
Giuseppe Pezzullo*
Federico Ravotti*

*: CERN

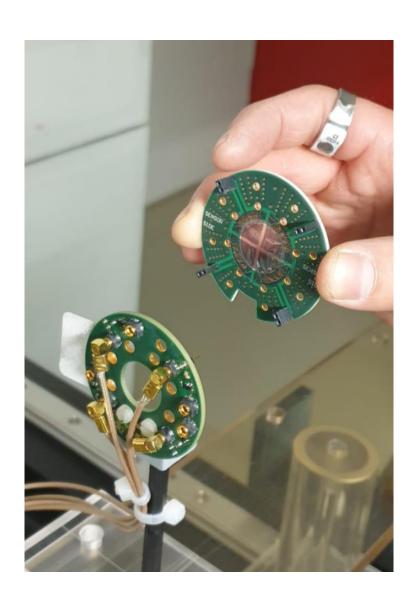


°: (Universita degli Studi di Trento and INFN (IT))

10th Beam Telescopes and Test Beams Workshop (Lecce, June 2022) https://indico.cern.ch/event/1058977/

Outline





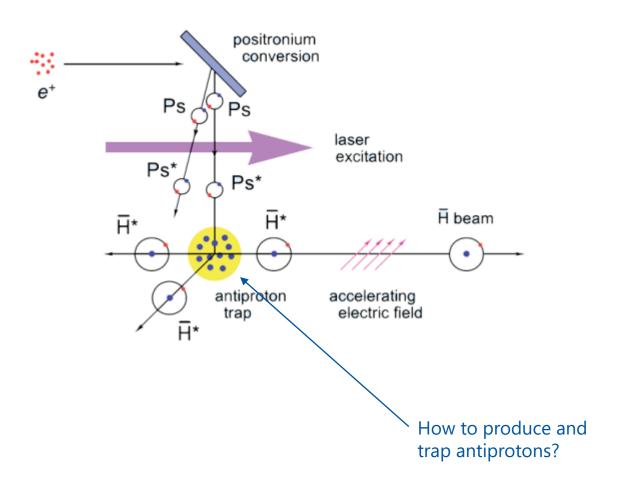
- The Aegis Experiment at the CERN Antimatter Factory
- Secondary Electron Emission: from theory to particle detectors:
- From Beam Position Monitor to Sensitive Degrader
- Test of the ultra thin BPM (nanoBPM)
- Development of a new BPM Front-End Electronics
- Test of the new BPM FE Electronics

The Aegis experiment at the CERN Antimatter Factory

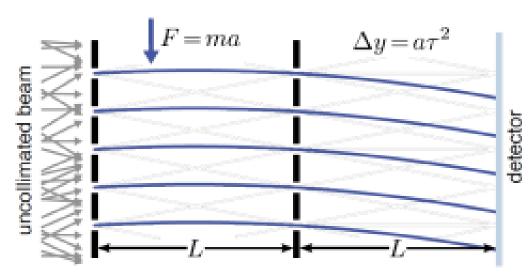


How to measure gravity with neutral antimatter?

1) Produce an anti-hydrogen beam

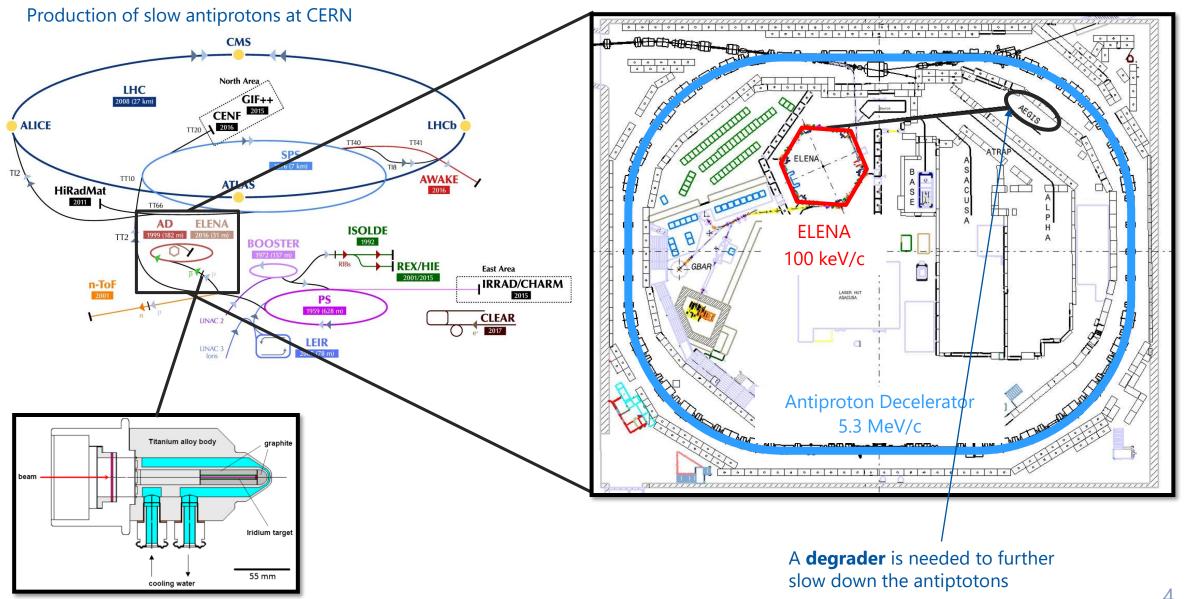


2) Let the anti-hydrogen fall





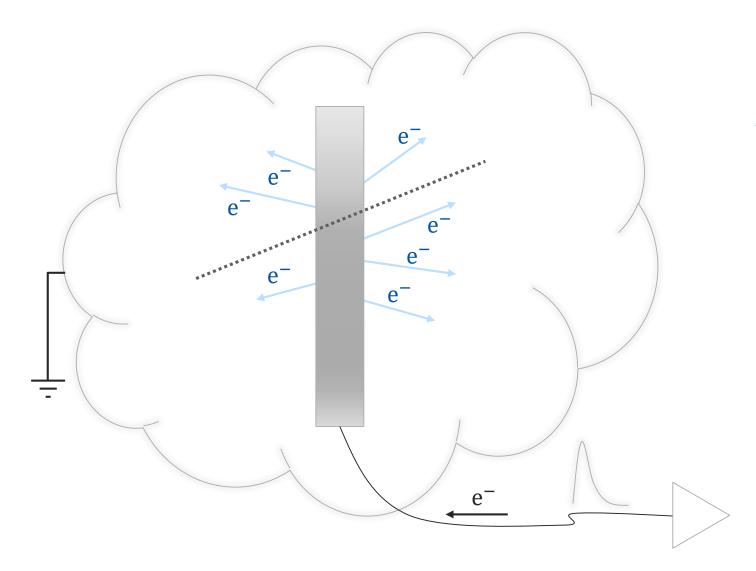
Aegis experiment at the CERN Antimatter Factory







It is possible to produce extremely thin particle detector using **Secondary Electron Emission**

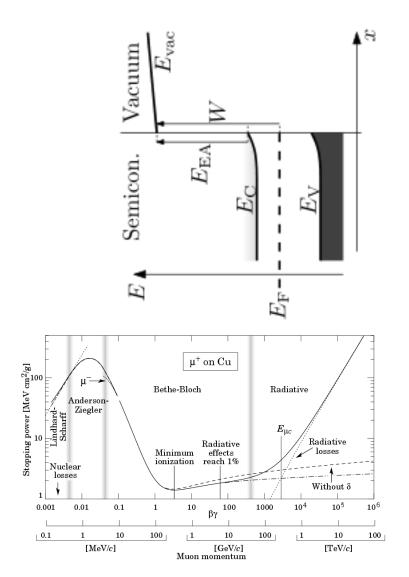


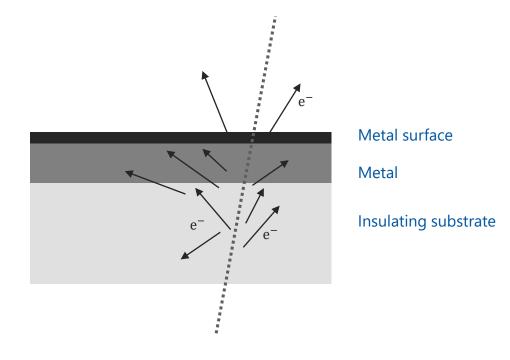
At the passage of a particle some electrons are emitted

If this is happening in a metal connected to ground, the emitted electrons will be replenished: the current generated by the metal will be proportional to the energy lost by the passing particle

Secondary Electron Emission







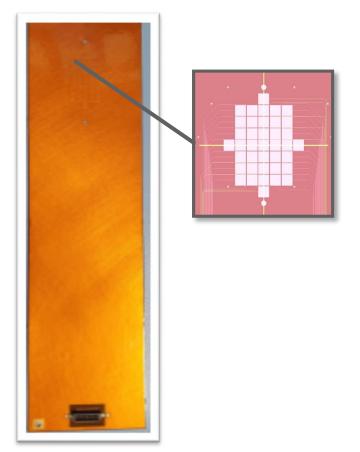
- The crossing particle loses energy
- Part of this energy can excite electrons
- Some of those electrons have enough energy to reach the surface
- Some of those electrons have enough energy to overcome the work function and they are emitted by the metal

Very inefficient process... ~1%

Secondary Electron Emission BPM @ IRRAD



The IRRAD team at CERN uses several BPM based on SEE

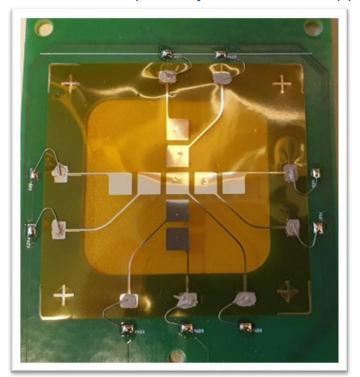


BPM (2010): 600 um Kapton + 140 um Cu



Extensive R&D for new generation sensors:

- Simpler production
- Higher radiation resistance
- Higher Secondary Emission Yield (SEY)
- Lower material activation
- Back compatibility with FE and mapping



uBPM: 25 um + 300 nm Al https://cds.cern.ch/record/2772583

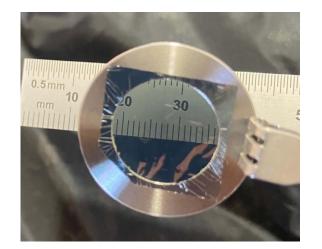
Front-end electronics of the BPM @ IRRAD



The electrons emitted by the sensor can be measured using a charge amplifier (integrator) M Pos: 990.0ms **CURSOR** Tek Stop: Type CONTROLLER When working with pulsed beams a gated Time integrator is used to improve the Signal to Noise Ratio (SNR) Source CH2 △t 1.200s **MULTIPLEXER** ± 833.3mHz △V. ?V. Cursor 1 **ADC** 1.04s 4.80V Hold Reset Select 2.24s 2V. 100pF CH1 5,00V CH2 5,00V M 250ms CH2 \(\) 2.00V CH4 100mV CINTERNAL CH3 5,00V 25-0ct-14 12:21 <10Hz Reset Sw In O-Hold O Sw Out The feedback capacitance (C_{INTERNAL}) is discharged by the reset signal (low), then it is collecting charge while the hold signal is low. O Sw Com Com O-After the integration, the integrated signal is digitized and stored

Is it possible to design a sensitive degrader?

It is possible to produce extremely thin particle detector using **Secondary Electron Emission**

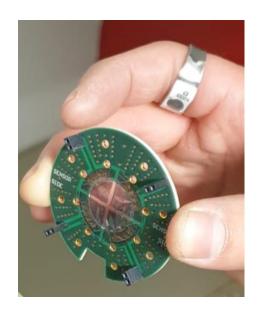


Parylene foil: thickness down to 100 nm

Why not add 10 nm of Al and read-out the SEE?

It is possible to deposit Al on the foil with a defined pattern



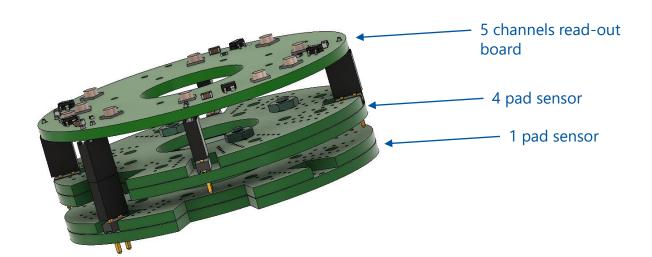


2 types of foils produced:

- 1 pad: 100 nm of parylene + 10 nm of Al
- 4 pad: 1500 nm of parylene + 10 nm of Al

2 additional sets of Mylar foils produced:

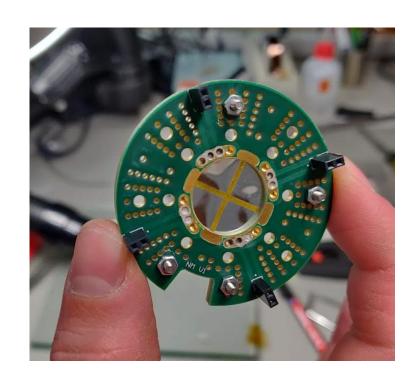
- 1 pad: 500 nm of Mylar + 10 nm of Al
- 4 pad: 900 nm of Mylar + 10 nm of Al

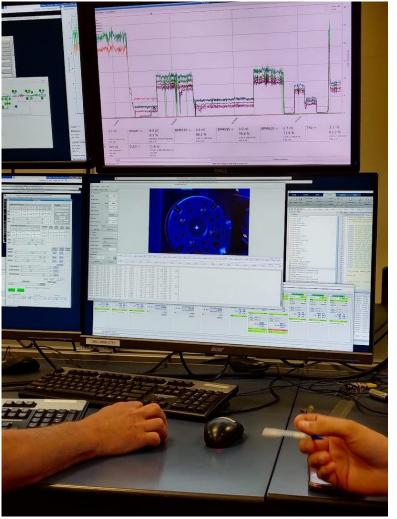


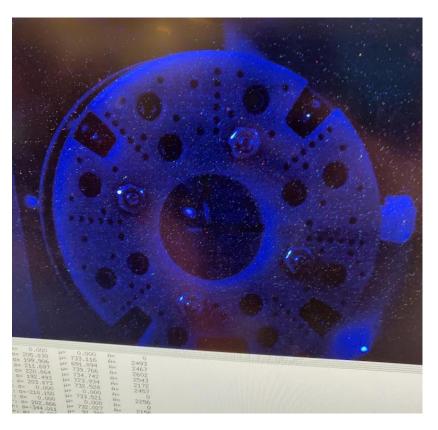




The proof-of-concept has been produced using aluminized Kapton and tested with 200 MeV electrons (~4 nC) @ CLEAR











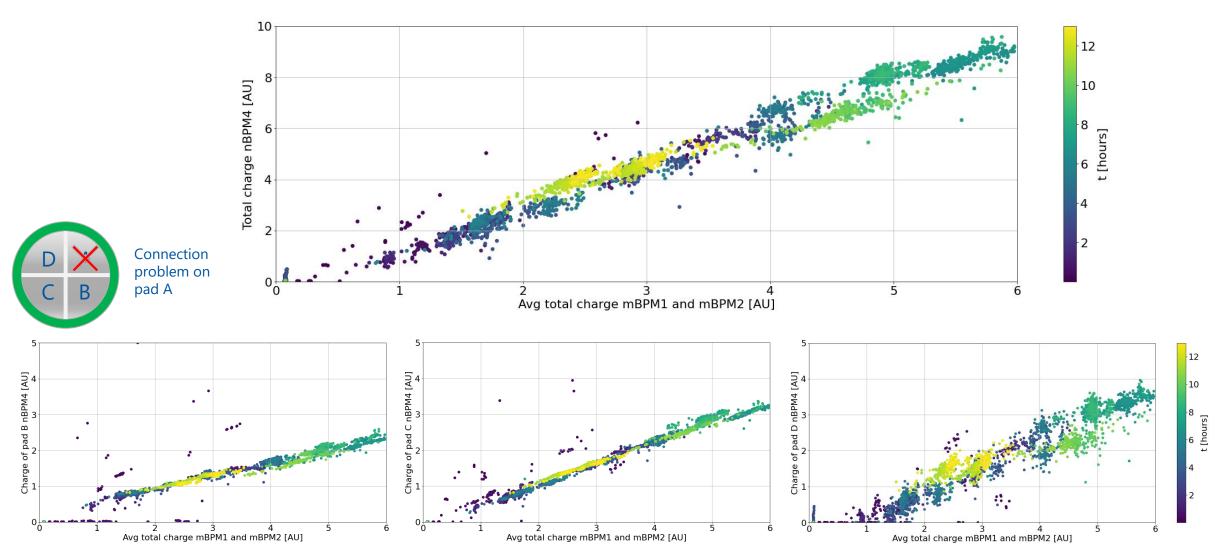
The nanoBPM was tested up to 6×10^{11} p/spill (400 ms) at the CERN IRRAD facility and compared with other BPM

nBPM: 1500 nm + 10 nm Al mBPM1 mBPM2 uBPM1 uBPM2 24 GeV/c p BPM2 BPM1 Movable table

Tests @ IRRAD

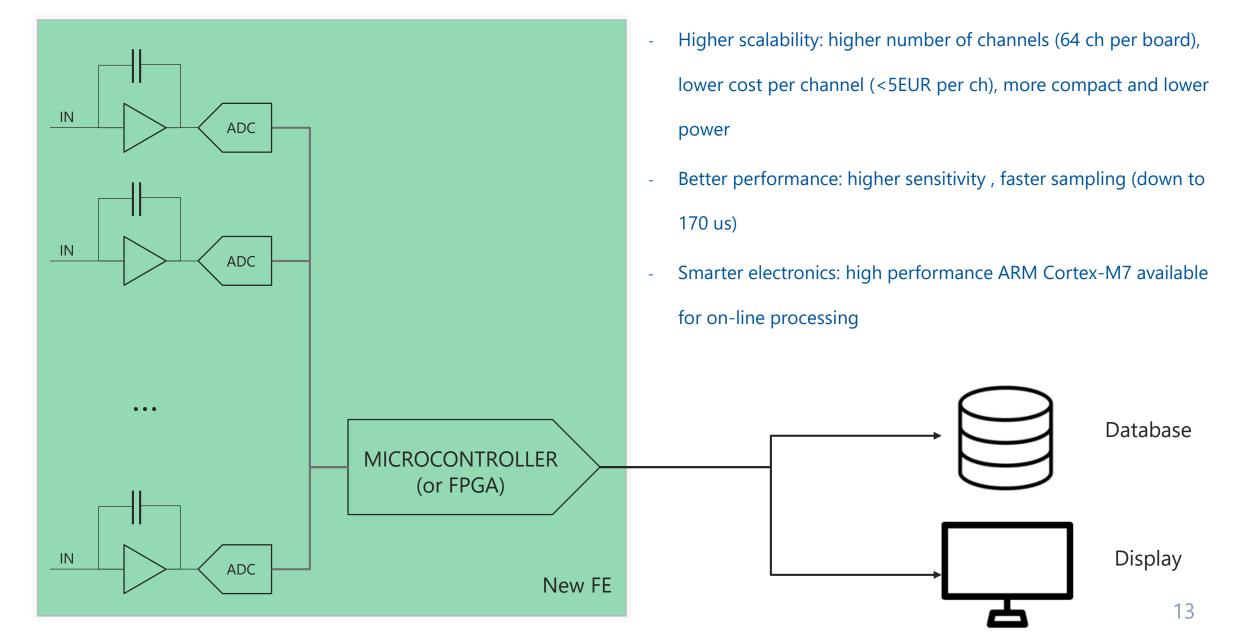


The nanoBPM was tested up to 6×10^{11} p/spill (400 ms) at the CERN IRRAD facility and compared with other BPM



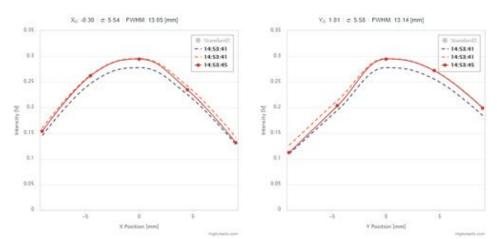
New Front-End Electronics





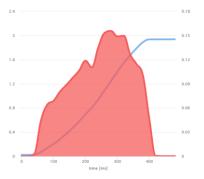
New Front-End Electronics: 8ch prototype





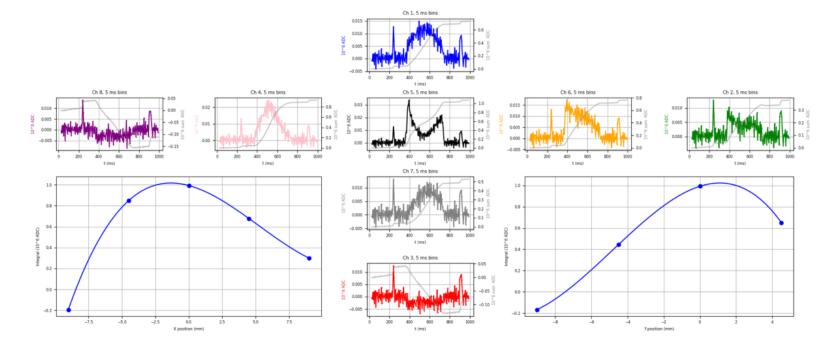
Present FE: 40 ch per board, measuring total charge per spill

Profile (20 ms sampling) available for a single channel



New FE: profile available for all channels with sampling down to 170 us (5ms in the picture)

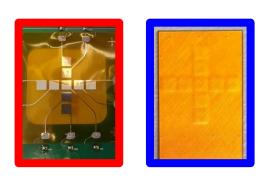


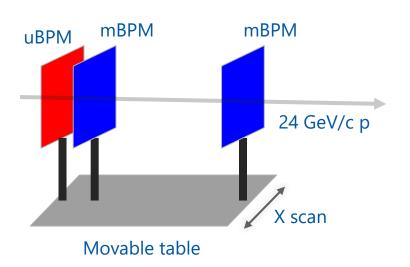


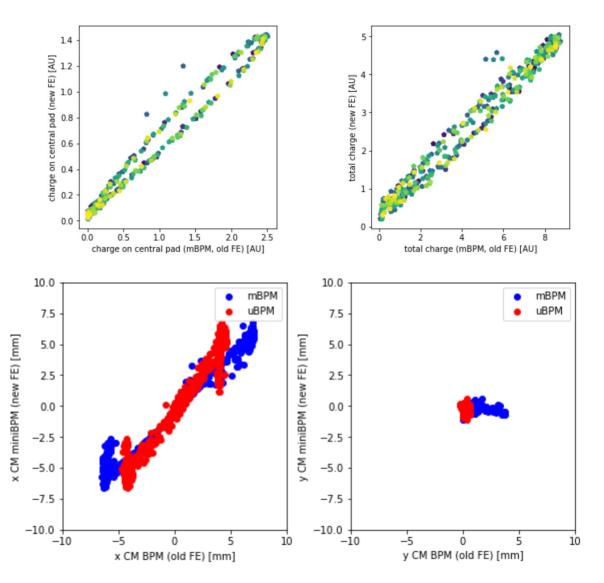
New FE Electronics: Correlations with old FE



Good correlation observed between the new and the present FE electronics



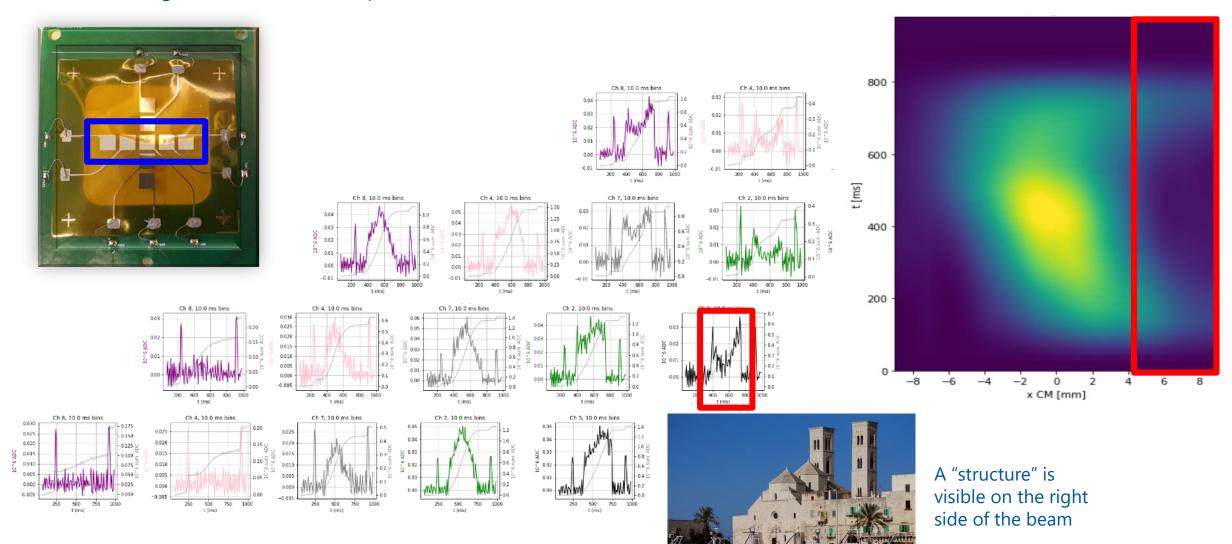




New FE Electronics: new observations possible



Thanks to the higher time resolution it is possible to observe new details of the beam structure



Conclusion and next steps



- Degrader/nanoBPM designed, manufactured
- Degrader/nanoBPM tested at IRRAD and performance compared with reference sensors

- New read-out electronics designed and produced (8 and 64 channels):

faster amplifier

- lower noise

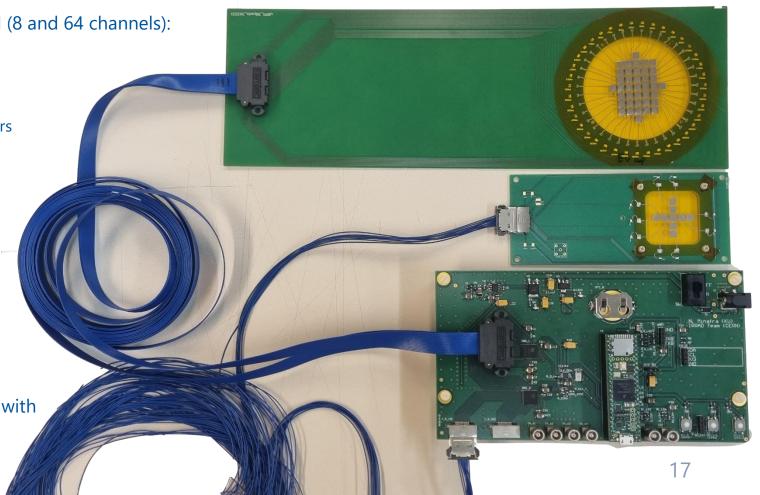
- more control on amplifier parameters

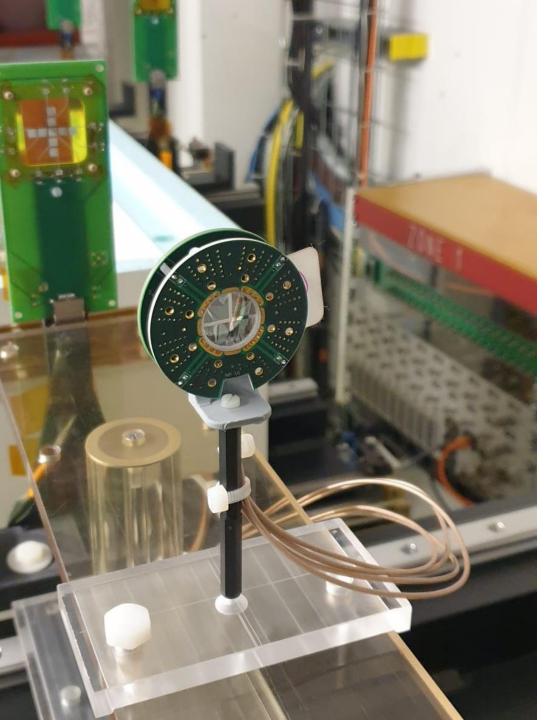
- Floating

Next steps:

- Test of the new Mylar nanoBPM
- Test of the nanoBPM with new FE electronics
- Test of the new 64 ch board
- Test of the nanoBPM inside the Aegis Experiment with

Antiproton beams







Ultra Thin Secondary Electron Emission Sensors for Beam Monitoring

Nicola Minafra (The University of Kansas (US))



Ruggero Caravita^o
Michael Doser*
Blerina Gkotse*
Stefan Haider*
Robert Loos*
Giuseppe Pezzullo*
Federico Ravotti*

*: CERN



°: (Universita degli Studi di Trento and INFN (IT))

10th Beam Telescopes and Test Beams Workshop (Lecce, June 2022) https://indico.cern.ch/event/1058977/